

Thermal and Magnetic-Field Stability of Holmium Single-Atom Magnets

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We use spin-polarized scanning tunneling microscopy to demonstrate that Ho atoms on magnesium oxide exhibit a coercive field of more than 8 T and magnetic bistability for many minutes, both at 35 K. The first spontaneous magnetization reversal events are recorded at 45 K, for which the metastable state relaxes in an external field of 8 T. The transverse magnetic anisotropy energy is estimated from magnetic field and bias voltage dependent switching rates at 4.3 K. Our measurements constrain the possible ground state of Ho single-atom magnets to either $J_z = 7$ or 8, both compatible with magnetic bistability at fields larger than 10 mT.

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Individual holmium atoms on magnesium oxide (MgO) thin films were identified as the first example of stable single-atom magnets [1]. They exhibit long-lived magnetic quantum states giving rise to remanent magnetization, representing the ultimate size limit of a magnetic bit [1]. While the reading and writing of individual Ho atoms were demonstrated [2], the thermal stability of their magnetization, their coercive field, and their magnetic ground state remain open issues. A further single-atom magnet system, Dy on graphene, was discovered [3]. It exhibits steps in magnetization curves due to magnetic level crossing, also characterizing molecular magnets [4]. The system Ho/MgO, however, is exceptional as there is no evidence of level crossing up to 8 T. Consequently, it can have a much larger remanence and an extremely high coercive field.

The first two single-atom magnet systems were explored using x-ray magnetic circular dichroism (XMCD) [1,3]. However, systems with long magnetic relaxation times are potentially perturbed by photon-induced secondary electrons that activate additional magnetic relaxation channels. The intrinsic relaxation time may be derived from flux dependent measurements and extrapolation to zero photon flux [5]. Independent of the method, measurements on ensembles with long-lived magnetic quantum states may probe state populations that are kinetically limited and thus deviate from thermodynamic equilibrium. As our measurements in the present Letter show, the magnetic saturation of an ensemble of Ho atoms on MgO might indeed be very difficult to achieve in a field sweep. The magnetization curves recorded by XMCD may consequently show a lower saturation, smaller hysteresis, and therewith derived magnetic moments would correspondingly appear smaller. This may explain the discrepancy to the Ho moment measured by electron-spin resonance (ESR) [2].

Scanning tunneling microscopy (STM) has been used to probe the magnetic states of Ho atoms via tunnel magnetoresistance (TMR) at bias voltages below a threshold of 73 meV [2]. Above this threshold the magnetic quantum states of Ho can be written. Here, we use this technique to establish new boundaries for the temperature and field dependent magnetic stability and for the magnetic ground state of Ho/MgO.

The measurements were performed with a homemade STM operating at temperatures from 0.4 to 50 K and in an out-of-plane magnetic field ($\mathbf{B}_z \parallel \mathbf{z}$) of up to 8 T [6,7]. We grow MgO on Ag(100) following recent literature [7,12]. After dosing Ho and Co atoms, we distinguish both species by their apparent height [see Figs. 1(a) and 1(b)] and identify Co atoms by their 58 meV spin-excitation signature [13]. We spin polarize (SP) a W tip by transferring Co adatoms to the tip apex and test the tip's SP along the z axis via pump-probe spectroscopy [14] on Co, which has a large out-of-plane anisotropy on MgO [13]. Figure 1(c) shows the typically achieved TMR of 21% [7] on Co and a spin-relaxation time of (25 ± 4) μ s at 4 T, in agreement with earlier results [15]. Once the tip's spin sensitivity is established, we use it to read and write the magnetic state of Ho atoms via the TMR [2]. We focus here on Ho atoms adsorbed on top of O in the MgO(100) lattice, which is the species exhibiting magnetic bistability [1,2]. We measure Ho atoms at constant current, and therefore a change in the magnetic state leads to a sudden jump in tip height [see Fig. 1(d)].

Figure 2 displays time traces of the tip height above Ho monitoring its magnetic state, UP or DOWN, at different temperatures and at 8 T. The degeneracy of these two states is lifted by the magnetic field, which is pointing UP (out of plane). The UP state is hence the ground state and DOWN the metastable state. Panel (a) illustrates the preparation of

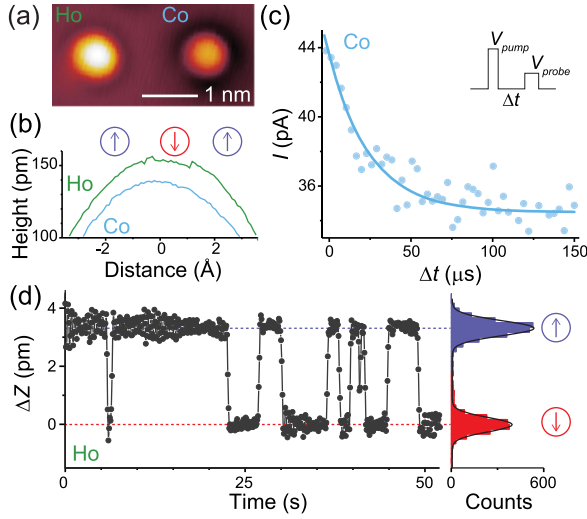


FIG. 1. (a) STM image of coadsorbed Ho and Co atoms on MgO/Ag(100). (b) Line profile of a Ho atom measured with a SP-tip at 150 mV showing apparent height contrast between the two magnetic states, as opposed to the profile across the paramagnetic Co atom. (c) Pump-probe measurement of the Co atom demonstrating spin polarization of the tip along the surface normal. (d) Telegraph signal in apparent height due to magnetic switching of a Ho atom. The histogram indicates a preference for one magnetization direction, identifying the magnetic ground state being UP in the external field pointing UP [(a)–(d) $B_z = 4$ T, $T_{\text{STM}} = 4.3$ K, $V = 150$ mV, $I = 50$ pA; (c) $V_{\text{pump}} = 150$ mV, $V_{\text{probe}} = 40$ mV].

a desired state. We start with the magnetization pointing DOWN. In order to reverse the magnetization to UP, we increase the tunnel voltage to 150 mV, leading to several consecutive switches between the two states and we lower the tunnel voltage back to 50 mV, once the atom is in the desired UP state. This probe voltage is lower than any of the electron-activated switching thresholds [2] and yields an

apparent height contrast of typically 2–4 pm between the Ho states. Figure 2(b) shows a tip-height time trace measured at 4.3 K, indicating two distinct levels corresponding to the Ho atom in the UP and DOWN state. The continuous tip-height trace shows that either state is stable for the several hundreds of seconds observation time. This is remarkable, given the large Zeeman energy difference of 9.36 meV between the UP and DOWN state, derived from the Ho magnetic moment of $(10.1 \pm 0.1) \mu_B$ [2]. The metastable Ho state withstands the opposing external magnetic field, which translates into an exceptional coercivity of at least 8 T for this single atom magnet.

Even more striking, magnetic bistability also extends to significantly higher temperatures. Figure 2(c) shows the tip-height time trace at 35 K. As for the case at 4.3 K, either state, UP and DOWN, is stable. We only see deliberate switching induced by current pulses at $V \geq 120$ mV. Figure 2(d) finally shows a few spontaneous magnetization reversals (green arrows) from the metastable to the ground state at 45 K. We measure a mean lifetime of the metastable state of 66^{+21}_{-15} s assuming an exponential residence time distribution according to expectations for a Markovian process. The high temperature required to activate thermal-induced switching further confirms the weak interaction between the magnetic quantum states and lattice vibrations. Note that above 50 K, Ho atoms start moving away from the oxygen to the bridge site of the MgO lattice [16], where they lose their single atom magnet properties, thus defining a natural temperature limit above which the system is irreversibly transformed, in agreement with previous observations [1].

In order to illuminate possible origins for the extraordinary stability of the Ho moment, we investigate the magnetic field dependent switching rate as a function of bias voltages above the switching threshold. We determine

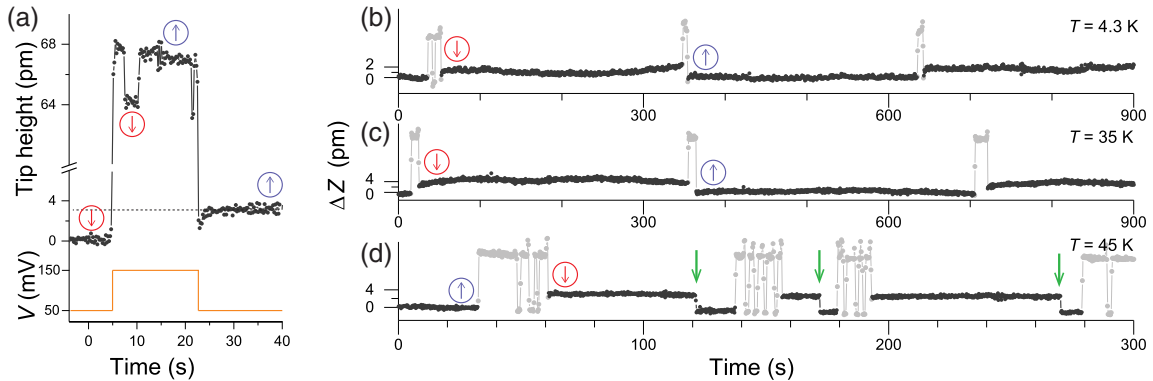


FIG. 2. Magnetic bistability of Ho atoms at elevated temperature and in an external field of $B_z = 8$ T pointing UP. (a) Intentional switching by increasing the tunnel voltage to $V = 150$ mV. (b) Tip-height time trace recorded at 4.3 K. The Ho moment is stable in both orientations. (c)–(d) Same as in (b) but measured at 35 and 45 K, respectively. While the metastable state remains essentially unaffected at 35 K, the onset of spontaneous reversals (green arrows) is seen at 45 K. (b)–(d) $V_{\text{monitor}} \leq 50$ mV, $V_{\text{switch}} \geq 120$ mV, and $I = 35$ pA. A linear background connecting segments of equal magnetic orientation was subtracted and a 3 Hz smoothing filter was applied.

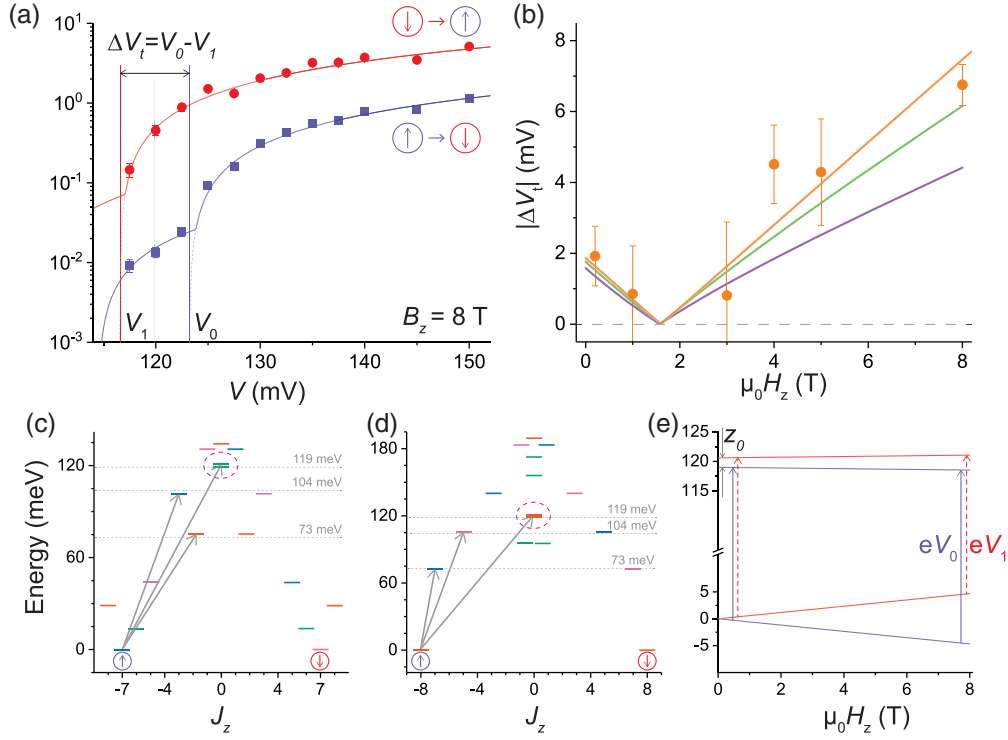


FIG. 3. Field dependent magnetic switching. (a) Semilog plot of the state resolved switching rate at $B_z = 8$ T, measured at 1.5 nA. The switching rates of the UP and DOWN states show the onset of a new rate increasing threshold at two different bias voltages V_0 and V_1 . The solid lines represent a linear fit above and below the threshold [7]. (b) Magnetic-field dependence of the threshold difference $|\Delta V_t|$, indicating a zero-field offset z_0 . The lines represent a fit to $|\Delta V_t| = |z_0 - 2\Delta m B_z|$ (orange), and show model calculations of a $J_z = 7$ (green) and $J_z = 8$ (purple) ground state at 10 mT [7]. The arrows and the horizontal lines denote the three thresholds reported in Ref. [2]. The dotted circles highlight the intermediate state with zero-field splitting z_0 . Levels of equal color are connected via the fourfold symmetry. (e) Zeeman energy sketch of the ground and intermediate states in dependence of applied field. Arrows indicate transitions from the ground state (blue) or the excited state (red) to the zero-field split intermediate state. All measurements were recorded at 4.3 K.

the switching rate from tip-height time traces, such as the one shown in Fig. 1(d), and separately quantify the lifetime of either state. Figure 3(a) shows the state resolved switching rate, from UP to DOWN and vice versa, at our maximal field of $B_z = 8$ T, measured for bias voltages between 117 and 150 mV. The switching rates of the ground state (blue) and metastable state (red) grow linearly with applied bias voltage due to the increasing fraction of tunnel electrons exceeding the switching threshold. We observe a rate increase at $V_0 = 123$ mV for the ground state, and at $V_1 = 116$ mV for the metastable state. The average value coincides with the state convoluted third threshold of (119 ± 1) mV reported in Ref. [2]. With respect to the latter work, our switching rates are ten times lower for this threshold, which we attribute to the transverse field applied in Ref. [2] and absent here, creating the atomic equivalent of spin-transfer torque [17]. The same holds for the thresholds at 73 and 104 mV [2], whose switching rates become too small to be quantified with significant statistics in our experiment. We find that the switching rate is reduced at higher magnetic field suggesting a reversal mechanism based on

electron-assisted quantum tunneling of the magnetization (QTM). As can be seen in Fig. 3(b), the threshold difference, $|\Delta V_t| = |V_0 - V_1|$, between the switching of the ground and metastable states, first shrinks from a distinct offset to zero and then increases with magnetic field when $V_1 > V_0$. We thus assume a zero-field splitting for the intermediate state and a linear Zeeman trend to which we fit the threshold difference $|\Delta V_t| = |z_0 - 2\Delta m B_z|$ [orange line in Fig. 3(b)]. We find a zero-field threshold difference of $z_0 = (1.8 \pm 0.8)$ mV and a magnetic moment difference Δm between the ground and intermediate states of $(9.5 \pm 1.1) \mu_B$. The 1.8 meV zero-field splitting in the intermediate state doublet results from the transverse anisotropy induced by the C_{4v} symmetry of the oxygen adsorption site. The measured Δm is compatible with the Ho ground state moment found previously [2]. Earlier XMCD measurements which derived $J_z = 4.7$ seemingly underestimated the magnetic moment of Ho [1], possibly due to the incomplete saturation of the ensemble in view of the extremely long-lived metastable state.

In view of these observations, we revise the Ho level scheme of Ref. [1] and propose two possible models, with

distinct ground state doublet $J_z = 7$ or 8 [7]. The $J_z = \pm 7$ case is symmetry protected from QTM and naturally compatible with magnetic bistability on the C_{4v} adsorption site [1,18]. The corresponding magnetic moment $m_{4f} = gJ_z\mu_B \approx 8.8\mu_B$, however, requires the presence of an additional $1.3\mu_B$ in an outer $6s/5d$ shell to match the Ho moment measured by ESR-STM [2]. We contrast the latter model to a $J_z = \pm 8$ scenario, for which the magnetic moment would be mostly localized on the $4f$ orbitals [2]. The latter ground state is stable only at a finite magnetic field. We reject cases of lower J_z for which the total magnetic moment observed by ESR STM cannot be matched.

In the effective spin-Hamiltonian analysis, detailed in the Supplemental Material [7], we formulate constraints for the magnetic level structures that are compatible with our $|\Delta V_i|$ data and earlier observations. We first tune the Stevens parameters to match the energy of the three previously reported switching thresholds [2] and to arrive at the largest rates for electron assisted QTM via these intermediate states [7,19]. In addition, we respect the absence of level crossings involving the ground state doublets up to 9 T [1]. The two corresponding energy level diagrams are shown for 10 mT in Figs. 3(c) ($J_z = 7$) and 3(d) ($J_z = 8$). At 10 mT, the $J_z = 8$ state is to 99.98% pure, whereas at 0.2 mT increased mixing reduces the purity to 95%. Within both models, the state switching described in this work would correspond to the transition between the legacy states $J_z = \pm 7 \rightarrow \pm 2$ or $J_z = \pm 8 \rightarrow \pm 4$ of an ideal uniaxial anisotropy case. In agreement with the present observations, both models have a large probability for reversing the Ho spin through the third threshold for all field values, whereas the lowest two transitions become strongly suppressed in an applied magnetic field. Within the error bar, both models reproduce our $|\Delta V_i|$ data. Unlike the symmetry protected $J_z = 7$ case, the $J_z = 8$ state relies on the large J quantum number and strong uniaxial anisotropy protecting the ground states [4]. The Zeeman energy overwhelms the transverse anisotropy term (Stevens parameter $B_4^4 < 4\mu\text{eV}$ [7]) for large J_z values already at a few milliteslas, leading to nearly degenerate ground states but to tunnel-split intermediate states of low J_z . Note that states of low J_z are mixed to lower order, resulting in the splitting seen in the level diagrams of Fig. 3. The externally applied field therefore lifts the mixing of the large J_z ground state doublet first, and effectively suppresses QTM. Holmium atoms of this $J_z = 8$ scenario would in fact not show bistability but rather be in a superposition of UP and DOWN state at zero field. In this case, the remanence observed in XMCD magnetization loops would have resulted from the slow dynamic of QTM-related switching that follows from the small transverse anisotropy. The weak coupling to MgO phonons may also suppress QTM, as observed for molecular magnets coupled to nanomechanical resonators [20]. In addition to the reorientation of the

magnetic moment via electrons from the STM tip and via thermal excitations, the state mixing may be a further alternative of how to control the spin state via the QTM [21] for an otherwise proven stable and coercive single atom magnet.

The combined thermal and magnetic-field stability reported here for the magnetic quantum states of single Ho atoms on MgO(100) surpasses the presently most stable molecular magnet dysprosocenium, reaching 60 K, but with very little remanence of $< 1\%$ M_{sat} and a short magnetic lifetime at high magnetic fields [22]. The suggested magnetic ground states for Ho are both intriguing candidates for quantum information processing and high density data storage applications; the $J_z = \pm 7$ state is ideally protected, while the $J_z = \pm 8$ state is stable only at a finite field, whereas at zero field it exhibits superposition states that are easy to manipulate.

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